



LM193 - Low Power Low Offset Voltage Dual Comparator



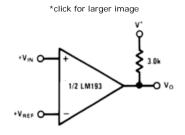
Features

• Wide supply

Voltage range:	2.0V to 36V
Single or dual supplies:	±1.0V to ±18V

Very low supply current drain (0.4 mA) - independent of supply voltage	
Low input biasing current:	25 nA
Low input offset current:	±5 nA
Maximum offset voltage:	±3 mV
Input common-mode voltage range includes ground	
Differential input voltage range equal to the power supply voltage	
Low output saturation voltage,:	250 mV at 4 mA
Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems	

Typical Application

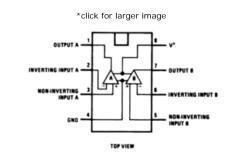


Parametric Table

Response Time	0.4 us
Output Bus	Open Drain
Supply Min	2 Volt
Supply Max	36 Volt
Channels	2 Channels
Offset Voltage max, 25C	2, 5 mV
Output Current	16 mA
Input Range	Vcm to V-
Supply Current Per Channel	0.2 mA
PowerWise Rating 3	80 uA x us

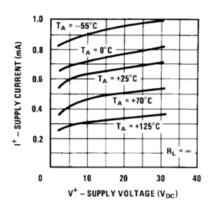
Typical Performance

Connection Diagram



Available in the 8-Bump (12 mil) micro SMD package	
See AN-1112 for micro SMD considerations	





Applications

- High precision comparators
- ullet Reduced V_{OS} drift over temperature
- Eliminates need for dual supplies
- Allows sensing near ground
- Compatible with all forms of logic
- Power drain suitable for battery operation

Datasheet



RoHS Compliance Information

LM193/LM293/LM393/LM2903 Low Power Low Offset Voltage Dual Comparators

LM193A/LM193QML Low Power Low Offset Voltage Dual Comparators

LM193JAN Low Power Low Offset Voltage Dual Comparators

LM193A/LM193QML Low Power Low Offset Voltage Dual Comparators

Package Availability, Models

Part Number		Package					Factory Lead Time		Models				Std Pack	Package Marking																	
T dit Number	Туре	Pins	Spec.	MSL Rating	Peak Reflow	RoHS Report		Weeks	Qty	Models					Format																
LM193AH	TO-99	8	STD	1	NA	RoHS		Full production		Full production		Full production		Full production		Full production		Full production		Full production		Full production		Full production		N/A				box of	NSZXYTTE# LM193AH
			NOPB	1	NA		6 weeks	1000				500																			
LM193H	TO-99	8	STD	1	_ NA	RoHS		Full produ	uction	N/A				box of	NSZXYTTE# LM193H																
LWIGOIT	. 0 00		NOPB	3 1 NA	NA	110110		6 weeks	2000					500	NOEXTITE# ENTOST																
LM193 MD8		Unp			Unpackaged Die			Full production		N/A				tray of	-																
						N/A	7500					N/A																			
LM193 MW8		Wafer					Full production		N/A	N/A			wafer jar of	-																	
						N/A	40000					N/A																			

General Description

The LM193 series consists of two independent precision voltage comparators with an offset voltage specification as low as 2.0 mV max for two comparators which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators also have a unique characteristic in that the input common-mode voltage range includes ground, even though operated from a single power supply voltage.

Application areas include limit comparators, simple analog to digital converters; pulse, squarewave and time delay generators; wide range VCO; MOS clock timers; multivibrators and high voltage digital logic gates. The LM193 series was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, the LM193 series will directly interface with MOS logic where their low power drain is a distinct advantage over standard comparators.

The LM393 and LM2903 parts are available in National's innovative thin micro SMD package with 8 (12 mil) large bumps.



LM193/LM293/LM393/LM2903 Low Power Low Offset Voltage Dual Comparators

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Advantages

- High precision comparators
- Reduced V_{OS} drift over temperature
- Eliminates need for dual supplies
- Allows sensing near ground
- Compatible with all forms of logic
- Power drain suitable for battery operation

Features

- Wide supply
 - Voltage range:Single or dual supplies:2.0V to 36V±1.0V to ±18V
- Very low supply current drain (0.4 mA) independent of supply voltage

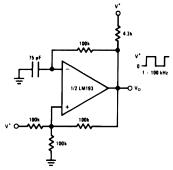
■ Low input biasing current: 25 nA

■ Low input offset current: ±5 nA

■ Maximum offset voltage: ±3 mV

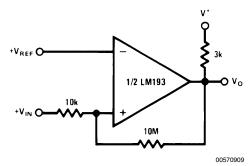
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Low output saturation voltage,: 250 mV at 4 mA
- Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems
- Available in the 8-Bump (12 mil) micro SMD package
- See AN-1112 for micro SMD considerations

Squarewave Oscillator

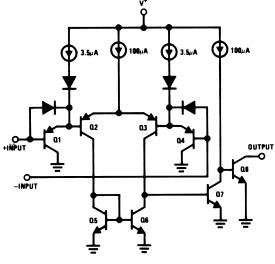


00570938

Non-Inverting Comparator with Hysteresis

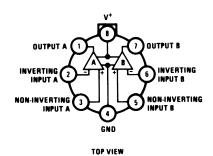


Schematic and Connection Diagrams



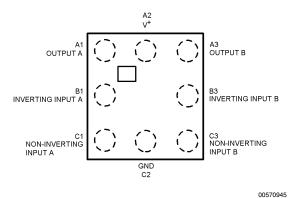
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Metal Can Package



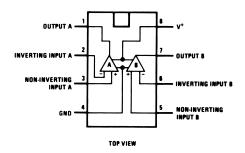
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micro SMD



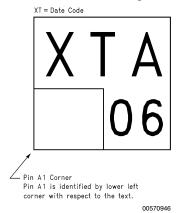
Top View

Dual-In-Line/SOIC Package



00570901

micro SMD Marking



Top View

Absolute Maximum Ratings (Note 10)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage, V $^+$ 36V Differential Input Voltage (Note 8) 36V Input Voltage -0.3V to +36V Input Current (V $_{\rm IN}$ <-0.3V) (Note 3) 50 mA Power Dissipation (Note 1)

Molded DIP780 mWMetal Can660 mWSmall Outline Package510 mWmicro SMD Pacakge568mW

Output Short-Circuit to Ground

(Note 2) Continuous

Operating Temperature Range

LM393 0°C to +70°C LM293 -25°C to +85°C Storage Temperature Range Lead Temperature

(Soldering, 10 seconds) +260°C

Soldering Information

Dual-In-Line Package
Soldering (10 seconds)

Small Outline Package

215°C

Vapor Phase (60 seconds)

Infrared (15 seconds) 220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD rating

 $(1.5 \text{ k}\Omega \text{ in series with } 100 \text{ pF})$ 1300V

Electrical Characteristics

 $(V^+=5V, T_A = 25^{\circ}C, unless otherwise stated)$

Parameter	Conditions			LM193/	A	Units
			Min	Тур	Max	
Input Offset Voltage	(Note 9)			1.0	2.0	mV
Input Bias Current	I _{IN} (+) or I _{IN}	(-) with Output In Linear		25	100	nA
	Range, V _C	_M = 0V (Note 5)				
Input Offset Current	I _{IN} (+)-I _{IN} (-) V _{CM} = 0V		3.0	25	nA
Input Common Mode	V+ = 30V ((Note 6)	0		V+-1.5	V
Voltage Range						
Supply Current	R _L =∞	V+=5V		0.4	1	mA
		V+=36V		1	2.5	mA
Voltage Gain	R _L ≥15 kΩ,	V ⁺ =15V	50	200		V/mV
	$V_O = 1V \text{ to}$	11V				
Large Signal Response	V _{IN} =TTL L	ogic Swing, V _{REF} =1.4V		300		ns
Time	V _{RL} =5V, R	$_{L}$ =5.1 k Ω				
Response Time	V _{RL} =5V, R	L=5.1 kΩ (Note 7)		1.3		μs
Output Sink Current	V _{IN} (-)=1V,	V _{IN} (-)=1V, V _{IN} (+)=0, V _O ≈1.5V		16		mA
Saturation Voltage	$V_{IN}(-)=1V, V_{IN}(+)=0, I_{SINK} \le 4 \text{ mA}$			250	400	mV
Output Leakage Current	V _{IN} (-)=0, \		0.1		nA	

Electrical Characteristics

(V⁺=5V, $T_A = 25$ °C, unless otherwise stated)

Parameter	Conditions	LM193		LM293, LM393				Units			
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Input Offset Voltage	(Note 9)		1.0	5.0		1.0	5.0		2.0	7.0	mV
Input Bias Current	$I_{IN}(+)$ or $I_{IN}(-)$ with Output In		25	100		25	250		25	250	nA
	Linear Range, V _{CM} = 0V (Note 5)										
Input Offset Current	$I_{IN}(+)-I_{IN}(-) V_{CM} = 0V$		3.0	25		5.0	50		5.0	50	nA
Input Common Mode	V+ = 30V (Note 6)	0		V+-1.5	0		V+-1.5	0		V+-1.5	V
Voltage Range											

Electrical Characteristics (Continued)

(V⁺=5V, $T_A = 25^{\circ}C$, unless otherwise stated)

Parameter	Conditions		LM193			LM293, LM393			LM2903			Units
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max]
Supply Current	R _L =∞	V+=5V		0.4	1		0.4	1		0.4	1.0	mA
		V+=36V		1	2.5		1	2.5		1	2.5	mA
Voltage Gain	R _L ≥15 kΩ, \	V ⁺ =15V	50	200		50	200		25	100		V/mV
	$V_O = 1V$ to	11V										
Large Signal Response	V _{IN} =TTL Lo	gic Swing, V _{REF} =1.4V		300			300			300		ns
Time	$V_{RL}=5V, R_{L}$	=5.1 kΩ										
Response Time	V_{RL} =5V, R_L	=5.1 kΩ (Note 7)		1.3			1.3			1.5		μs
Output Sink Current	$V_{IN}(-)=1V,$	$V_{IN}(+)=0, V_O \le 1.5V$	6.0	16		6.0	16		6.0	16		mA
Saturation Voltage	$V_{IN}(-)=1V,$	V _{IN} (+)=0, I _{SINK} ≤4 mA		250	400		250	400		250	400	mV
Output Leakage Current	$V_{IN}(-)=0, V$	$_{IN}(+)=1V, V_{O}=5V$		0.1			0.1			0.1		nA

Electrical Characteristics

(V+ = 5V) (Note 4)

Parameter	Conditions		LM193A					
		Min	Тур	Max				
Input Offset Voltage	(Note 9)			4.0	mV			
Input Offset Current	$I_{IN(+)} - I_{IN(-)}, V_{CM} = 0V$			100	nA			
Input Bias Current	I _{IN} (+) or I _{IN} (-) with Output in Linear Range,			300	nA			
	V _{CM} =0V (Note 5)							
Input Common Mode	V ⁺ =30V (Note 6)	0		V ⁺ -2.0	V			
Voltage Range								
Saturation Voltage	$V_{IN}(-)=1V, V_{IN}(+)=0, I_{SINK} \le 4 \text{ mA}$			700	mV			
Output Leakage Current	$V_{IN}(-)=0, V_{IN(+)}=1V, V_O=30V$			1.0	μA			
Differential Input Voltage	Keep All V _{IN} 's≥0V (or V ⁻ , if Used), (Note 8)			36	V			

Electrical Characteristics

(V+ = 5V) (Note 4)

Parameter	Conditions		LM193			293, L	M393		Units		
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Input Offset Voltage	(Note 9)			9			9		9	15	mV
Input Offset Current	$I_{IN(+)} - I_{IN(-)}, V_{CM} = 0V$			100			150		50	200	nA
Input Bias Current	I _{IN} (+) or I _{IN} (-) with Output in Linear Range, V _{CM} =0V (Note 5)			300			400		200	500	nA
Input Common Mode Voltage Range	V+=30V (Note 6)	0		V ⁺ -2.0	0		V+-2.0	0		V ⁺ -2.0	V
Saturation Voltage	$V_{IN}(-)=1V, V_{IN}(+)=0,$ $I_{SINK} \le 4 \text{ mA}$			700			700		400	700	mV
Output Leakage Current	$V_{IN}(-)=0, V_{IN(+)}=1V, V_{O}=30V$			1.0			1.0			1.0	μA
Differential Input Voltage	Keep All V _{IN} 's≥0V (or V ⁻ , if Used), (Note 8)			36			36			36	V

Note 1: For operating at high temperatures, the LM393 and LM2903 must be derated based on a 125°C maximum junction temperature and a thermal resistance of 170°C/W which applies for the device soldered in a printed circuit board, operating in a still air ambient. The LM193/LM193A/LM293 must be derated based on a 150°C maximum junction temperature. The low bias dissipation and the "ON-OFF" characteristic of the outputs keeps the chip dissipation very small ($P_D \le 100 \text{ mW}$), provided the output transistors are allowed to saturate.

Note 2: Short circuits from the output to V⁺ can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 20 mA independent of the magnitude of V⁺.

Note 3: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action

Electrical Characteristics (Continued)

on the IC chip. This transistor action can cause the output voltages of the comparators to go to the V^+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3V.

Note 4: These specifications are limited to $-55^{\circ}C \le T_A \le +125^{\circ}C$, for the LM193/LM193A. With the LM293 all temperature specifications are limited to $-25^{\circ}C \le T_A \le +85^{\circ}C$ and the LM393 temperature specifications are limited to $0^{\circ}C \le T_A \le +70^{\circ}C$. The LM2903 is limited to $-40^{\circ}C \le T_A \le +85^{\circ}C$.

Note 5: The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the reference or input lines.

Note 6: The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V^+ -1.5V at 25°C, but either or both inputs can go to 36V without damage, independent of the magnitude of V^+ .

Note 7: The response time specified is for a 100 mV input step with 5 mV overdrive. For larger overdrive signals 300 ns can be obtained, see typical performance characteristics section.

Note 8: Positive excursions of input voltage may exceed the power supply level. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state. The low input voltage state must not be less than -0.3V (or 0.3V below the magnitude of the negative power supply, if used).

Note 9: At output switch point, $V_0 \approx 1.4V$, $R_S = 0\Omega$ with V^+ from 5V to 30V; and over the full input common-mode range (0V to $V^+ = 1.5V$), at 25°C.

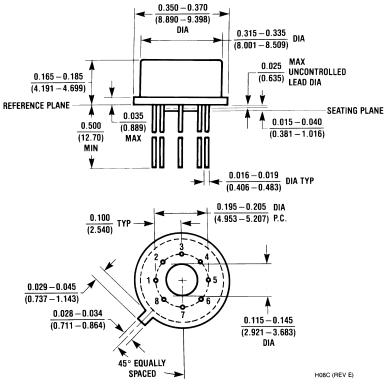
Note 10: Refer to RETS193AX for LM193AH military specifications and to RETS193X for LM193H military specifications.

Ordering Information

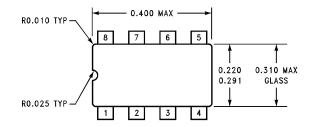
Package	Temperature Range	•						
		LM193H*						
		LM193H/883						
		LM193H-MLS						
	−55°C to 125°C							
8-Pin Metal Can		LM193AH-QMLV**	H08C					
		LM193AH						
		LM193AH/883						
	−25°C to 85°C	LM293H						
	0°C to 70°C	LM393H						
		LM193J/883*						
8-Pin Ceramic DIP	FF°C += 10F°C	LM193AJ/883	100 A					
8-Pin Ceramic DIP	−55°C to 125°C	J08A						
		LM193AJ-MLS						
8-Pin Molded DIP	0°C to 70°C	LM393N	N08E					
o-Pin Wolded DIP	–40°C to 85°C	LM2903N	NOOE					
	0°C to 70°C	LM393M						
8-Pin SOIC	0 0 10 70 0	LM393MX	M08A					
0-1111 3010	-40°C to 85°C	LM2903M	WOOA					
	-40 C to 65 C	LM2903MX						
	0°C to 70°C	LM393TL						
8-Bump (12 mils)	0 0 10 70 0	0°C to 70°C LM393TLX						
micro SMD	-40°C to 85°C	LM2903ITL	- TLA08AAA					
	-40 C 10 65 C	1						

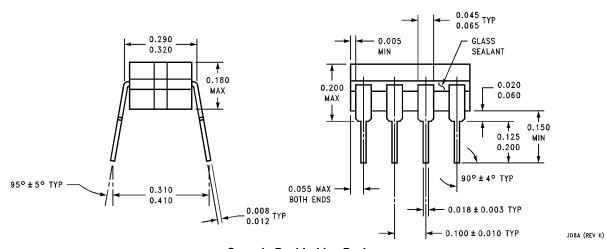
Note: * Also available per LM38510/11202 **Note:** ** See STD Mil DWG 5962-94526

Physical Dimensions inches (millimeters) unless otherwise noted



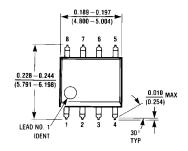
Metal Can Package (H) NS Package Number H08C

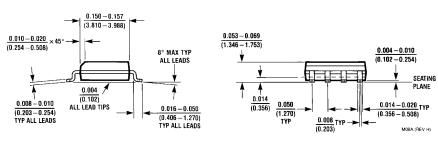




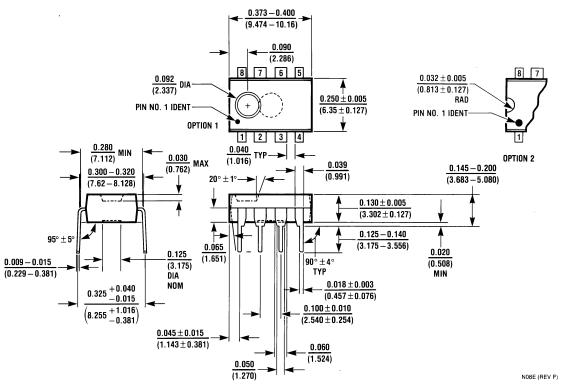
Ceramic Dual-In-Line Package NS Package Number J08A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





SOIC Package NS Package Number M08A



Molded Dual-In-Line Package (N)
NS Package N08E